# **CBT3253A**

# Dual 1-of-4 FET multiplexer/demultiplexerRev. 01 — 24 October 2005Pr

**Product data sheet** 

#### **General description** 1.

The CBT3253A is a dual 1-of-4 high-speed TTL-compatible FET multiplexer/demultiplexer. The low on-resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise.

10E, 20E, S0, and S1 select the appropriate B output for the A-input data.

The CBT3253A is characterized for operation from -40 °C to +85 °C.

#### 2. **Features**

- **5**  $\Omega$  switch connection between two ports
- TTL-compatible input levels
- Minimal propagation delay through the switch
- ESD protection exceeds 2000 V HBM per JESD22-A114, 200 V MM per JESD22-A115 and 1000 V CDM per JESD22-C101
- Latch-up testing is done to JEDEC Standard JESD78 which exceeds 100 mA

#### **Ordering information** 3.

#### Table 1: Ordering information 10°C to 195°C

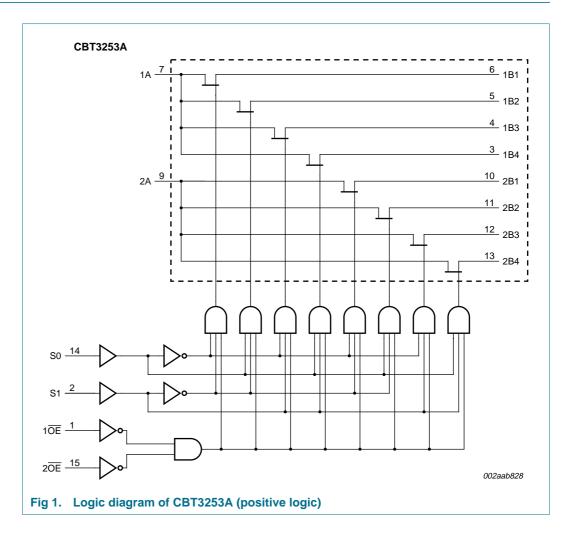
	$T_{amb} = -40$ °C to +85 °C						
Type number	Topside	Package					
	mark	Name	Description	Version			
CBT3253AD	CBT3253AD	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			
CBT3253ADB	C3253A	SSOP16	plastic shrink small outline package; 16 leads; body width 5.3 mm	SOT338-1			
CBT3253ADS	CT3253A	SSOP16 <sup>[1]</sup>	plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm	SOT519-1			
CBT3253APW	CT3253A	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1			

[1] Also known as QSOP16.



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### 4. Functional diagram



### 5. Pinning information

#### 5.1 Pinning

10E 1	1	6 V <sub>CC</sub>				
S1 2 1B4 3 1B3 4 1B2 5 1B1 6 1A 7	CBT3253AD	5 20E 4 S0 3 2B4 2 2B3 1 2B2 0 2B1 	10E 1 S1 2 1B4 3 1B3 4 1B2 5 1B1 6 1A 7 GND 8	CBT3253ADB	16 V <sub>CC</sub> 15 2OE 14 S0 13 2B4 12 2B3 11 2B2 10 2B1 9 2A	
	GND 8 9 2A 002aab824 Fig 2. Pin configuration for SO16			002aab825       Fig 3. Pin configuration for SSOP16		
10E 1 S1 2 1B4 3 1B3 4 1B2 5 1B1 6 1A 7 GND 8	CBT3253ADS	16       V <sub>CC</sub> 15       2OE         14       S0         13       2B4         12       2B3         11       2B2         10       2B1         9       2A	10E 1 S1 2 1B4 3 1B3 4 1B2 5 1B1 6 1A 7 GND 8	CBT3253APW	16       V <sub>CC</sub> 15       2OE         14       S0         13       2B4         12       2B3         11       2B2         10       2B1         9       2A	
002aab826 Fig 4. Pin configuration for SSOP16 (QSOP16)			Fig 5. Pin c	002aab		

#### 5.2 Pin description

#### Table 2: **Pin description** Symbol Pin Description 1<sub>OE</sub> 1 output enable (active LOW) S1 2 select-control input 1B4, 1B3, 1B2, 1B1 3, 4, 5, 6 B outputs [1] 1A 7 A input GND 8 ground (0 V) 2A 9 A input 2B1, 2B2, 2B3, 2B4 10, 11, 12, 13 B outputs S0 select-control input 14 20E 15 output enable (active LOW) V<sub>CC</sub> 16 positive supply voltage [1] B outputs are inputs if A inputs are outputs.

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#### 6. Functional description

Refer to Figure 1 "Logic diagram of CBT3253A (positive logic)"

#### 6.1 Function selection

Table 3:Function selection

Inputs			Function			
10E	2OE	S1	S0			
Х	Н	Х	Х	disconnect 1A and 2A		
Н	Х	Х	Х	disconnect 1A and 2A		
L	L	L	L	1A to 1B1 and 2A to 2B1		
L	L	L	Н	1A to 1B2 and 2A to 2B2		
L	L	Н	L	1A to 1B3 and 2A to 2B3		
L	L	Н	Н	1A to 1B4 and 2A to 2B4		

#### 7. Limiting values

#### Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5 <sup>[1]</sup>	+7.0	V
I <sub>CCC</sub>	continuous current through each V <sub>CC</sub> or GND pin		-	128	mA
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-	-50	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

### 8. Recommended operating conditions

#### Table 5: Operating conditions

All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage		4.5	-	5.5	V
VIH	HIGH-state input voltage	)	2	-	-	V
V <sub>IL</sub>	LOW-state input voltage		-	-	0.8	V
T <sub>amb</sub>	ambient temperature	operating in free air	-40	-	+85	°C

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#### 9. Static characteristics

#### Table 6: Static characteristics

 $T_{amb} = -40 \circ C$  to +85  $\circ C$ 

Symbol	Parameter	Conditions	Min	Тур <mark>[1]</mark>	Мах	Unit
V <sub>IK</sub>	input clamping voltage	$V_{CC} = 4.5 \text{ V}; I_I = -18 \text{ mA}$	-	-	-1.2	V
V <sub>pass</sub>	pass voltage	$V_I = V_{CC} = 5.5 \text{ V}; I_O = -100 \ \mu\text{A}$	3.4	3.6	3.9	V
I <sub>LI</sub>	input leakage current	$V_{CC}$ = 5 V; $V_{I}$ = 5.5 V or GND	-	-	±1	μΑ
I <sub>CC</sub>	quiescent supply current	$V_{CC}$ = 5.5 V; I <sub>O</sub> = 0 mA; V <sub>I</sub> = V <sub>CC</sub> or GND	-	-	3	μΑ
$\Delta I_{CC}$	additional quiescent supply current (control inputs)	$V_{CC}$ = 5.5 V; one input at 3.4 V; other inputs at $V_{CC}$ or GND	[2] _	-	2.5	mA
Ci	input capacitance (control pins)	$V_1 = 3 V \text{ or } 0 V$	-	4.5	-	рF
C <sub>io(off)</sub>	off-state input/output	A port; $V_0 = 3 V \text{ or } 0 V$ ; $\overline{OE} = V_{CC}$	-	23.5	-	pF
	capacitance	B port; $V_0 = 3 V \text{ or } 0 V$ ; $\overline{OE} = V_{CC}$	-	6.5	-	pF
R <sub>on</sub>	ON-state resistance [3]	$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 64 \text{ mA}$	-	5	7	Ω
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 0 \text{ V}; \text{ I}_{I} = 30 \text{ mA}$	-	5	7	Ω
		$V_{CC} = 4.5 \text{ V}; \text{ V}_{I} = 2.4 \text{ V}; \text{ I}_{I} = -15 \text{ mA}$	-	10	15	Ω

[1] All typical values are at V<sub>CC</sub> = 5 V, T<sub>amb</sub> = 25 °C.

[2] This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.

[3] Measured by the voltage drop between the A and the B terminals at the indicated current through the switch. ON-state resistance is determined by the lowest voltage of the two (A or B) terminals.

#### **10.** Dynamic characteristics

#### Table 7: Dynamic characteristics

 $V_{CC}$  = +5.0 V ± 0.5 V;  $T_{amb}$  = -40 °C to +85 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t <sub>PD</sub>	propagation delay	from input (nA or nBn) to output (nBn or nA)	<u>[1]</u> _	-	0.25	ns
		from input (Sn) to output (nA or nBn)	1.2	-	6.2	ns
t <sub>en</sub>	enable time <sup>[2]</sup>	from input (Sn) to output (nA or nBn)	1.3	-	6.3	ns
		from input $(n\overline{OE})$ to output (nA or nBn)	1.4	-	6.4	ns
t <sub>dis</sub>	disable time 3	from input (Sn) to output (nA or nBn)	1.1	-	7.2	ns
		from input $(n\overline{OE})$ to output (nA or nBn)	1.0	-	7	ns

[1] The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

[2] Output enable time to HIGH and LOW level.

[3] Output disable time from HIGH and LOW level.

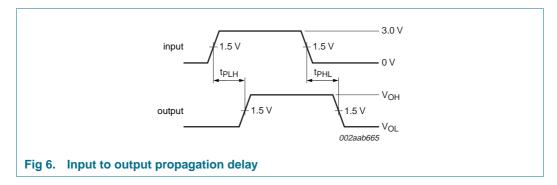
#### 10.1 AC waveforms

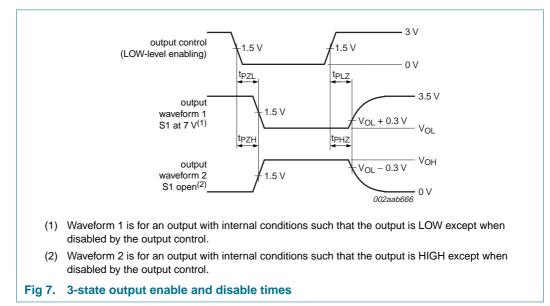
 $V_I = GND$  to 3.0 V.

 $t_{\mathsf{PLZ}}$  and  $t_{\mathsf{PHZ}}$  are the same as  $t_{\mathsf{dis}}.$ 

 $t_{\text{PZL}}$  and  $t_{\text{PZH}}$  are the same as  $t_{\text{en}}.$ 

 $t_{\mathsf{PLH}}$  and  $t_{\mathsf{PHL}}$  are the same as  $t_{\mathsf{PD}}.$ 





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### **11. Test information**

	from output under test $C_L$ $C_L$ $R_L$ $R_L$ $C_L$ $R_L$ $R_L$ $C_L$ $R_L$ $R_L$ $C_L$ $R_L$
	Test data are given in Table 8.
	All input pulses are supplied by generators having the following characteristics: PRR $\leq$ 10 MHz; Z <sub>0</sub> = 50 $\Omega$ ; t <sub>r</sub> $\leq$ 2.5 ns; t <sub>f</sub> $\leq$ 2.5 ns.
	The outputs are measured one at a time with one transition per measurement.
	$C_L$ = load capacitance includes jig and probe capacitance.
	$R_L$ = load resistance.
Fiq 8.	Test circuit

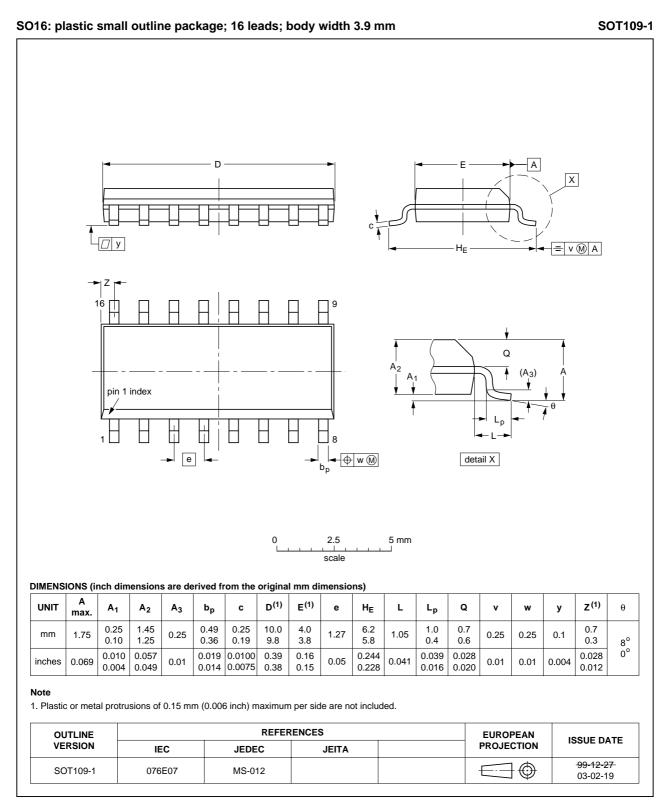
#### Table 8: Test data

Test	Load		Switch	
	CL	RL		
t <sub>PD</sub>	50 pF	500 Ω	open	
t <sub>PLZ</sub> , t <sub>PZL</sub>	50 pF	500 Ω	7 V	
t <sub>PHZ</sub> , t <sub>PZH</sub>	50 pF	500 Ω	open	

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#### 12. Package outline



#### Fig 9. Package outline SOT109-1 (SO16)

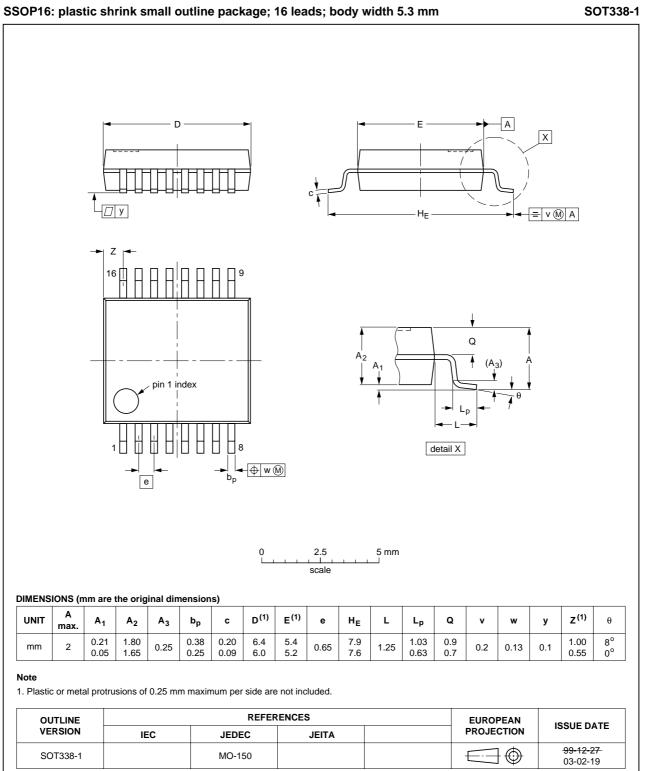
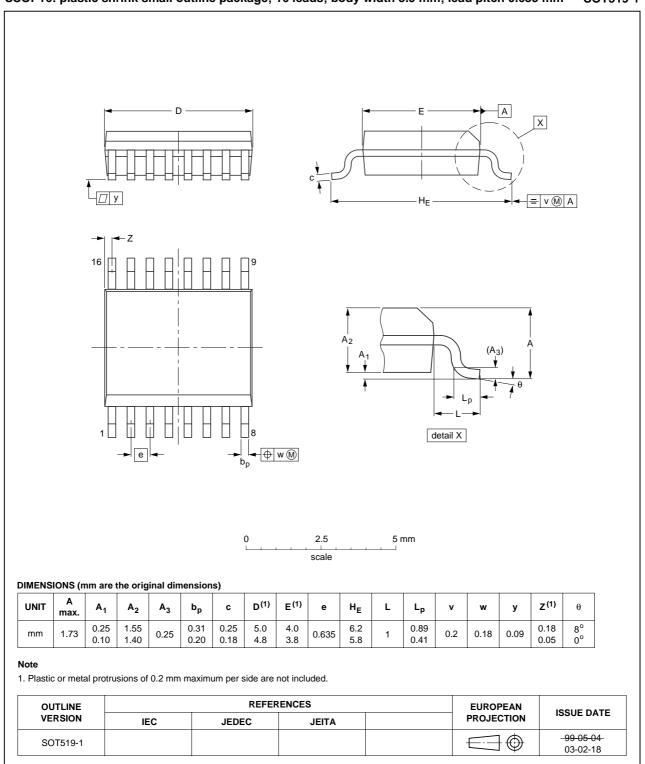
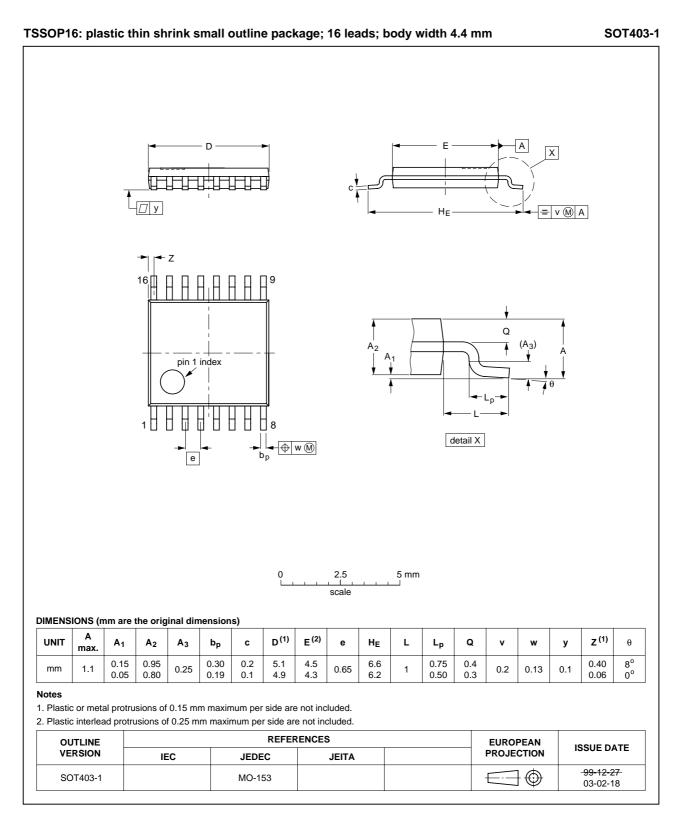


Fig 10. Package outline SOT338-1 (SSOP16)



#### SSOP16: plastic shrink small outline package; 16 leads; body width 3.9 mm; lead pitch 0.635 mm SOT519-1

Fig 11. Package outline SOT519-1 (SSOP16)



#### Fig 12. Package outline SOT403-1 (TSSOP16)

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#### 13. Soldering

#### **13.1** Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *Data Handbook IC26; Integrated Circuit Packages* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering can still be used for certain surface mount ICs, but it is not suitable for fine pitch SMDs. In these situations reflow soldering is recommended.

#### 13.2 Reflow soldering

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement. Driven by legislation and environmental forces the worldwide use of lead-free solder pastes is increasing.

Several methods exist for reflowing; for example, convection or convection/infrared heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 seconds and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 °C to 270 °C depending on solder paste material. The top-surface temperature of the packages should preferably be kept:

- below 225 °C (SnPb process) or below 245 °C (Pb-free process)
  - for all BGA, HTSSON..T and SSOP..T packages
  - for packages with a thickness  $\geq$  2.5 mm
  - for packages with a thickness < 2.5 mm and a volume ≥ 350 mm<sup>3</sup> so called thick/large packages.
- below 240 °C (SnPb process) or below 260 °C (Pb-free process) for packages with a thickness < 2.5 mm and a volume < 350 mm<sup>3</sup> so called small/thin packages.

Moisture sensitivity precautions, as indicated on packing, must be respected at all times.

#### 13.3 Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;

 smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time of the leads in the wave ranges from 3 seconds to 4 seconds at 250 °C or 265 °C, depending on solder material applied, SnPb or Pb-free respectively.

A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### 13.4 Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to 300  $^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 seconds to 5 seconds between 270  $^\circ C$  and 320  $^\circ C.$ 

#### **13.5** Package related soldering information

Package [1]	Soldering method		
	Wave	Reflow <sup>[2]</sup>	
BGA, HTSSONT <sup>[3]</sup> , LBGA, LFBGA, SQFP, SSOPT <sup>[3]</sup> , TFBGA, VFBGA, XSON	not suitable	suitable	
DHVQFN, HBCC, HBGA, HLQFP, HSO, HSOP, HSQFP, HSSON, HTQFP, HTSSOP, HVQFN, HVSON, SMS	not suitable <sup>[4]</sup>	suitable	
PLCC <sup>[5]</sup> , SO, SOJ	suitable	suitable	
LQFP, QFP, TQFP	not recommended [5] [6]	suitable	
SSOP, TSSOP, VSO, VSSOP	not recommended [7]	suitable	
CWQCCNL <sup>[8]</sup> , PMFP <sup>[9]</sup> , WQCCNL <sup>[8]</sup>	not suitable	not suitable	

 For more detailed information on the BGA packages refer to the (LF)BGA Application Note (AN01026); order a copy from your Philips Semiconductors sales office.

- [2] All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods.
- [3] These transparent plastic packages are extremely sensitive to reflow soldering conditions and must on no account be processed through more than one soldering cycle or subjected to infrared reflow soldering with peak temperature exceeding 217 °C ± 10 °C measured in the atmosphere of the reflow oven. The package body peak temperature must be kept as low as possible.

- [4] These packages are not suitable for wave soldering. On versions with the heatsink on the bottom side, the solder cannot penetrate between the printed-circuit board and the heatsink. On versions with the heatsink on the top side, the solder might be deposited on the heatsink surface.
- [5] If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- [6] Wave soldering is suitable for LQFP, QFP and TQFP packages with a pitch (e) larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- [7] Wave soldering is suitable for SSOP, TSSOP, VSO and VSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.
- [8] Image sensor packages in principle should not be soldered. They are mounted in sockets or delivered pre-mounted on flex foil. However, the image sensor package can be mounted by the client on a flex foil by using a hot bar soldering process. The appropriate soldering profile can be provided on request.
- [9] Hot bar soldering or manual soldering is suitable for PMFP packages.

#### 14. Abbreviations

Table 10: Abbreviations		
Acronym	Description	
CDM	Charged Device Model	
ESD	ElectroStatic Discharge	
FET	Field-Effect Transistor	
HBM	Human Body Model	
MM	Machine Model	
PRR	Pulse Rate Repetition	
TTL	Transistor-Transistor Logic	

### 15. Revision history

Table 11: Revision history						
Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes	
CBT3253A_1	20051024	Product data sheet	-	9397 750 12919	-	

#### Dual 1-of-4 FET multiplexer/demultiplexer

#### 16. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

### **17. Definitions**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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